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New [1]benzothieno[3,2-*b*]benzothiophene-tetraoxide-based TADF emitters with a D-A-D structure for OLED applications[†]

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Luminescent organic molecules showing thermally activated delayed fluorescence (TADF) are appealing materials for high-efficiency OLEDs. Here, we report a new class of organic luminescent materials with TADF properties, and a D-A-D electronic structure based on [1]benzothieno[3,2-*b*]benzothiophene-tetraoxide BTBTO₄ as the acceptor unit A. Three donor units D were selected and coupled with BTBTO₄, using a straightforward synthetic protocol based on microwave-assisted Buchwald–Hartwig cross-coupling, to yield three organic luminescent molecules labelled **PTz₂-BTBTO₄**, **MPA₂-BTBTO₄** and **POC_z₂-BTBTO₄**. Chemico-physical and structural properties were investigated by cyclic voltammetry, electrical measurements, crystallographic analysis, theoretical study and photophysical characterization. All three emitters showed high electrochemical stability with reversible oxidation waves. **MPA₂-BTBTO₄** was selected as the reference molecule for X-ray analysis, which revealed torsion angles of -59° and 86° between the donor (MPA) and acceptor (BTBTO₄) units supporting their appropriate structural configuration to have TADF properties. Photophysical studies highlighted a noteworthy increase in PL efficiency upon deoxygenation for all three compounds. The oxygen-induced quenching of delayed fluorescence and time-resolved photoluminescence studies supported the presence of the TADF properties, further corroborated for **PTz₂-BTBTO₄** and **MPA₂-BTBTO₄** by DFT studies. Preliminary steady-state photophysical studies were also carried out on neat films of all three emitters, revealing a pronounced self-quenching of photoluminescence for **PTz₂-BTBTO₄** and **MPA₂-BTBTO₄** and a minimal self-quenching for **POC_z₂-BTBTO₄**, which maintains a high Φ_{PL} (22%) comparable to that in Zeonex and half of that in PMMA. As a proof of concept, the three emitting molecules were tested as neat films in simple-structure OLED devices. In accordance with the photoluminescence data, **POC_z₂-BTBTO₄**, thanks to its sterically bulky structure, retains a good emission capacity even in a neat film and was also selected as an active matrix to build OLED devices by using two different deposition techniques: inkjet-printing and spin coating.

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1. Introduction

Organic light emitting diodes (OLEDs) represent a successful technology with applications in flat panel displays and solid-state lighting thanks to their excellent properties including facile fabrication, lightweight construction, low cost, facile colour tunability, low turn-on voltages and high flexibility.^{1–3} Commercial products such as smartphones and televisions based on this technology are currently present on the market. However, continuous progress is still necessary and existing open challenges include mainly enhancement of luminescence yields, saving operating energy, cheaper and easier preparation of organic emitting materials, lower costs and simplification of device architecture. First-generation OLEDs based on fluorescent emitters are limited to 25% of internal EL quantum efficiency (IQE), since they are able to harvest only singlet excitons. In phosphorescent materials,^{4–6} heavy metal atoms are required to ensure strong spin-orbit coupling (SOC), facilitating efficient intersystem crossing (ISC) between singlet (S_1) and triplet (T_1) electronic states, thereby allowing triplet excitons to become emissive. However, these systems typically rely on the use of precious metals such as Ir and Pt, and hence metal-free alternatives are highly desirable. Moreover, compared with fluorescent materials, the stability of phosphorescent materials^{7–9} is often unsatisfactory. On the other hand, TADF materials^{10–12} are purely organic compounds, characterized by the presence of efficient reverse intersystem crossing (RISC) between the nearly degenerate S_1 and T_1 excited electronic states. The singlet-triplet energy barrier (ΔE_{ST}) is comparable with the $k_B T$ at room temperature, allowing the RISC process to occur. A very small ΔE_{ST} in TADF materials is generally achieved using a twisted donor-acceptor (D-A) architecture, where D is an electron-donor unit and A is an electron-acceptor unit, characterized by the presence of a charge transfer (CT) state where the highest occupied molecular orbital (HOMO) and the lowest unoccupied molecular orbital (LUMO) are separated on different moieties of the molecule. Furthermore, in TADF materials, the presence of ^1CT states (vibronically coupled with ^3LE states), or in some cases n-p* states, also allows increasing SOC, further facilitating the ISC/RISC process. The strategy to harvest emission from the triplet excitons appears to be the most promising, due to these materials being generally metal-free and usually easy to synthesize and process, as well as relatively low-cost. A common molecular design strategy to obtain TADF materials includes a D- π -A structural architecture, with π being a π -conjugated bridge.^{13–19} Other architectures include D- σ -A configurations,^{20–22} with σ being a non-conjugated linker or a fused polycyclic heteroaromatic structure.^{23–25} Since the pioneering work of Adachi *et al.*¹⁰ in exploiting the TADF properties in metal-free organic materials for OLEDs, a large number of TADF organic materials have been reported in the literature. These are most often based on D-A,^{26–30} D-A-D,^{31–34} D-A-D',^{35–39} D-A-A^{40–42} and D-A-A'³² architectures. On the other hand, the electronic features affect the twisted D-A framework of TADF materials, hence the amplitude of ΔE_{ST} and therefore the final efficiency in devices. Chi *et al.*⁴³ reported interesting results in the study of D-A structures based on dibenzo[a,c]phenazine as an electron acceptor and triphenylamine as an electron donor. To gain insights into the

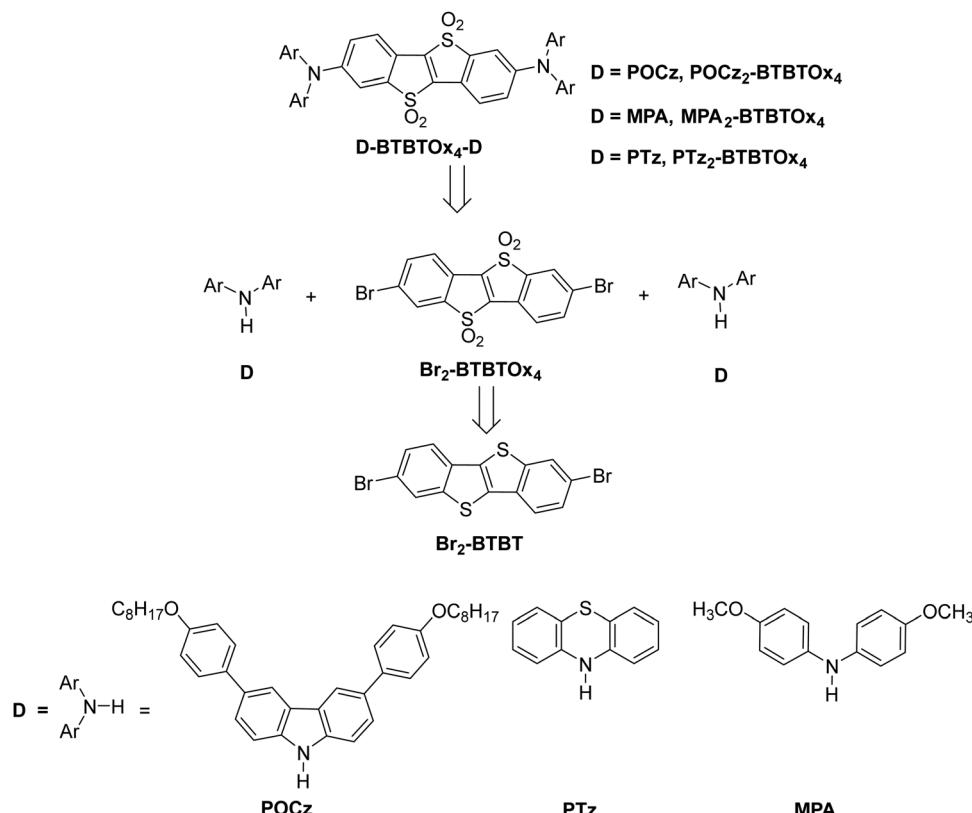
structure–property correlation, they synthesized three molecules with different frameworks of D-A, D-A-D and D-A-A and analysed the effects on photophysical and electroluminescence properties originated from the structural variations of the basic D-A framework. The results show that the introduction of an additional donor or acceptor unit reduces ΔE_{ST} , promotes RISC and enhances the photoluminescence quantum yield, providing useful insight into the rational molecular design of efficient TADF materials. From a synthetic standpoint TADF emitters with a D-A-D framework are usually easier to design and prepare and the challenge of creating new efficient TADF emitters based on simple molecular structures that are synthesizable by low cost enabling technologies is still open. Furthermore, the chemical structure of organic emitting materials plays a key role in the processing conditions and then in the complexity of the OLED structure. Organic materials processable from solution for neat-film-based OLEDs are highly desirable as they allow fabrication of simplified final devices based on a reduced number of components and simple processing conditions.⁴⁴ Aryl-sulfone-derivatives have been widely investigated as suitable electron-acceptor units in TADF emitters.^{15,44–53} They are very attractive in the D-A-D framework and the corresponding TADF emitters also show very good performance in non-doped devices, highlighting the high potential of pristine films for OLED application. Aryl-sulfone planar units based on heteroaryl fused rings have also been investigated as a structural strategy to reduce exciton annihilation by increasing the rigidity of the electron-acceptor unit A.^{54–58} [1]Benzothieno[3,2-*b*]benzothiophene BTBT is a very intriguing polycyclic heteroaromatic planar framework, mainly investigated in field effect transistors^{58–61} for its excellent charge mobility and, to a lesser extent, as a π -bridge in DSSC solar cells.⁶² This moiety can be obtained in high yield with a simple synthetic protocol suitable for large-scale production. At the same time, the two thienyl rings can be easily oxidized to yield the *S,S*-tetraoxide derivative, converting the molecule into an electron-acceptor unit that is potentially useful in D-A-D TADF systems. Herein we report the results of our studies on three new TADF emitters with a D-A-D structure, based on [1]benzothieno[3,2-*b*]benzothiophene-tetraoxide BTBT-Ox₄ as the electron-acceptor unit A and three different electron-donor units D. Phenothiazine, dimethoxyphenylamine and a carbazole derivative were selected as donor units D to prepare the final materials. New BTBT-Ox₄-based small molecules were prepared following a straightforward synthetic protocol based on the microwave-assisted Buchwald–Hartwig reaction. They were then characterized by cyclic voltammetry, photo-CELIV measurements, crystallographic analysis, and theoretical and photophysical studies. Photophysical studies revealed the TADF properties in this new class of organic emitting materials and as a proof of concept they were tested as neat emissive layers in solution-processed OLED devices.

2. Results and discussion

2.1 Synthetic procedure

Scheme 1 shows the retrosynthetic procedure followed to prepare the final emitting materials (**PTz₂-BTBT₂Ox₄**, **MPA₂-BTBT₂Ox₄**, and





Scheme 1 Retrosynthetic pathway towards organic emitting materials **POCz₂-BTBTO₄**, **PTz₂-BTBTO₄** and **MPA₂-BTBTO₄**.

POCz₂-BTBTO₄). The synthesis was accomplished by the Hartwig–Buchwald amination of $\text{Br}_2\text{-BTBTO}_4$ with two equivalents of the corresponding donor units, *i.e.* phenothiazine (PTz) for **PTz₂-BTBTO₄**, 4,4'-dimethoxydiphenylamine (MPA) for **MPA₂-BTBTO₄** and a carbazole derivative (POCz) for **POCz₂-BTBTO₄**. $\text{Pd}_2\text{dba}_3\cdot\text{CHCl}_3$ and $\text{P}(t\text{-Bu})_3$ were used as the catalytic system, sodium *tert*-butylate as the base and toluene as the solvent. The reactions were performed in a microwave reactor at 110 °C for 1 h. Compound $\text{Br}_2\text{-BTBTO}_4$ was synthesized by oxidation of 2,7-dibromo-[1]benzothieno[3,2-*b*]benzothiophene $\text{Br}_2\text{-BTBT}$ ⁶³ with hydrogen peroxide in chloroform and trifluoroacetic acid.

All details about the synthetic procedures and chemico-structural characterization are reported in the ESI.† The synthetic protocol is very straightforward and the final step to obtain the emitting materials can be performed in a short time and with high yield using the microwave-assisted Buchwald–Hartwig reaction. Electronic and chemico-structural characteristics determined the choice of donor units, starting from phenothiazine (PTz) to 4,4'-dimethoxydiphenylamine (MPA), to the carbazole derivative POCz. Phenothiazine is a heterocycle compound with a strong electron-donor behaviour and a non-planar butterfly shaped bent structure.^{64–66} 4,4'-Dimethoxydiphenylamine is a strong donor unit widely used in D-π-D molecular semiconductors,^{67–72} characterized by a non-planar and less rigid structure than the phenothiazine. The carbazole derivative POCz, bis-3,6-(4-octyloxyphenyl)-carbazole, was designed as the donor unit with a more complex molecular structure, combining the carbazole with two octyloxyphenyl units able to enhance the electron donor power

of carbazole and at the same time to modulate, by steric effects of aliphatic chains, the aggregation properties in the solid state of the final emitting material.

2.2 Cyclic voltammetry

We investigated the electrochemical properties of the BTBTO₄-based emitters BTB by cyclic voltammetry (CV) measurements (Fig. 1).

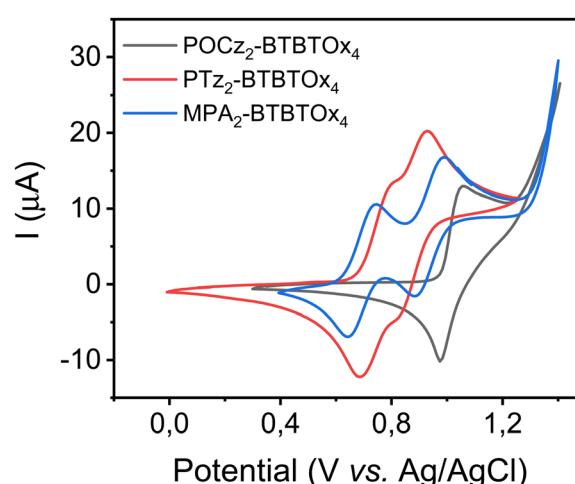


Fig. 1 CV curves of organic emitting materials **POCz₂-BTBTO₄**, **PTz₂-BTBTO₄** and **MPA₂-BTBTO₄**.



Table 1 Electrochemical properties and corresponding energy levels^a of **POCz₂-BTBTO_x₄**, **PTz₂-BTBTO_x₄** and **MPA₂-BTBTO_x₄**

Compound	$E_{1/2}(1)$ (mV)	$E_{1/2}(2)$ (mV)	E_{HOMO}^c (eV)	E_{LUMO}^d (eV)	$E_g^{\text{opt}} e$ (eV)
POCz₂-BTBTO_x₄	566	627 ^b	-5.70	-3.04	2.67
PTz₂-BTBTO_x₄	367	487	-5.42	-2.70	2.72
MPA₂-BTBTO_x₄	296	536	-5.35	-2.97	2.39

^a $c = 1 \times 10^{-3}$ in $\text{CH}_2\text{Cl}_2/\text{TBAPF}_6$ (0.1 M), half-wave potentials calculated from the CVs of Fig. 1 and referenced to the Fc^+/Fc couple ($E_{1/2} = 434$ mV) at 50 mV s^{-1} . ^b The potentials of **POCz₂-BTBTO_x₄** were estimated by differential pulse voltammetry (DPV, see Fig. S4.4, ESI). DPV condition: modulation amplitude 5 mV; modulation time 0.05 s; interval time (Δt) 0.5 s; step potential (E_{step}) 0.005 V; scan rate $\nu = E_{\text{step}}/\Delta t$ 0.01 V s^{-1} . ^c $E_{\text{HOMO}} = -(E_{\text{onset}} + 516)$ (eV). ^d $E_{\text{LUMO}} = E_{\text{HOMO}} - E_g^{\text{opt}}$ (eV). ^e E_g^{opt} was estimated by absorption onset.

All three compounds show two redox oxidation processes, and the values were found to be 1.00 and 1.06 V for **POCz₂-BTBTO_x₄**, 0.80 and 0.92 V for **PTz₂-BTBTO_x₄** and 0.73 and 0.97 V for **MPA₂-BTBTO_x₄** vs. Ag/AgCl, respectively. The highest occupied molecular orbital (HOMO) energy levels were estimated to be -5.70, -5.42 and -5.35 eV for **POCz₂-BTBTO_x₄**, **PTz₂-BTBTO_x₄** and **MPA₂-BTBTO_x₄**, respectively. The lowest unoccupied molecular orbital (LUMO) energy levels were calculated from the HOMO levels and the optical energy gaps, and found to be -3.04, -2.70 and -2.97 eV for **POCz₂-BTBTO_x₄**, **PTz₂-BTBTO_x₄** and **MPA₂-BTBTO_x₄**, respectively. The data are reported in Table 1.

2.3 Charge carrier mobility

In the present work we used the photo-CELIV technique that has been developed and used for measuring the charge mobility of organic layers in the direction perpendicular to the film,⁷³ which is the direction most relevant for photovoltaic applications or light emitting diodes.^{74,75} In Fig. 2 the photo-CELIV responses of an ITO/POCz₂-BTBTO_x₄ or PTz₂-BTBTO_x₄ or MPA₂-BTBTO_x₄/Al device are shown. Transients were acquired by optically pumping the sample at a wavelength of 450 nm and detected as a voltage drop by using an external load. A wavelength of 450 nm was chosen to provide a bulk photo-excitation for an accurate measurement of the mobility.⁷⁶ The time delay, maximum ramp voltage, pulse duration, and the external resistor were varied accordingly in order to optimize the signal to noise ratio.⁷⁷ The photo-CELIV response is characterized by a

sharp increase, rectangular current transient (J_0), and a slowly growing current (ΔJ) whose maximum depends on the applied ramp voltage. By using peak time (t_{max}) values we were able to determine the carrier mobility according to the equation below, which is valid in the case of volume photogeneration and a drift current maximum (ΔJ) lower than the displacement current (J_0):⁷⁸

$$\mu = \frac{2d^2}{3At_{\text{max}}^2}$$

where d is the sample thickness and A is the ramp speed (voltage/ramp duration). In the present case, the **PTz₂-BTBTO_x₄** compound is characterized by the lower mobility value $5.2 \times 10^{-8} \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$, meanwhile both **MPA₂-BTBTO_x₄** and **POCz₂-BTBTO_x₄** have similar mobility $1.1 \times 10^{-6} \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$, at a speed of around 2×10^3 (V s⁻¹). Regarding the latter case, we can clearly observe that the higher PLQY correlates with a good charge carrier mobility, making **POCz₂-BTBTO_x₄** a suitable candidate for OLED applications.

2.4 X-ray powder diffraction (XRPD) analysis

XRPD patterns were collected using a Rigaku RINT2500 rotating anode diffractometer (50 kV, 200 mA) equipped with a silicon strip Rigaku D/teX Ultra detector. An asymmetric Johansson Ge(111) crystal was used to select the monochromatic Cu K α 1 radiation ($\lambda = 1.54056 \text{ \AA}$). Measurements were executed in transmission mode by introducing the sample in a Lindemann glass capillary tube with a diameter of 0.5 mm. The XRPD patterns were recorded in the 2θ range of 4–60° for **POCz₂-BTBTO_x₄** and **PTz₂-BTBTO_x₄** and of 6–100° for **MPA₂-BTBTO_x₄**, by step scanning, using 2θ increments of 0.02° and a fixed counting time of 2 s per step. The diffraction pattern of **POCz₂-BTBTO_x₄** revealed the amorphous nature of the material (see Fig. S5.1, ESI[†]), that, consequently, could not be characterized *via* an *ab initio* structure solution process. To check the novelty and phase purity of **PTz₂-BTBTO_x₄** and **MPA₂-BTBTO_x₄**, a qualitative analysis using the powder diffraction data was carried out *via* the software QUALX2.0,⁷⁹ aimed at identifying the presence of one (or more) known crystal phase stored in the POW_COD database.⁷⁹ The qualitative analysis revealed that the two compounds were unpublished so far. For both, the structure solution process was attempted by EXPO;⁸⁰ the full pathway (*i.e.*, indexing, space group determination, extraction of the

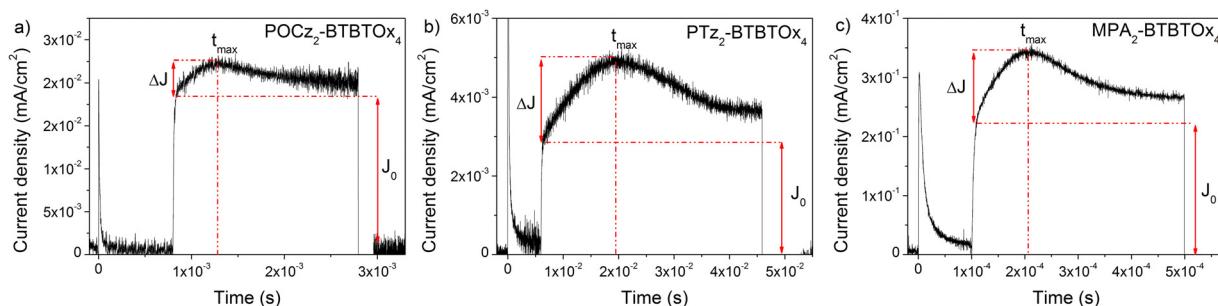


Fig. 2 Photo-CELIV transients on ITO/POCz₂-BTBTO_x₄ or PTz₂-BTBTO_x₄ or MPA₂-BTBTO_x₄/Al devices. Measurements were performed in vacuum, at room temperature, at a ramp speed of around 2×10^3 (V s⁻¹).



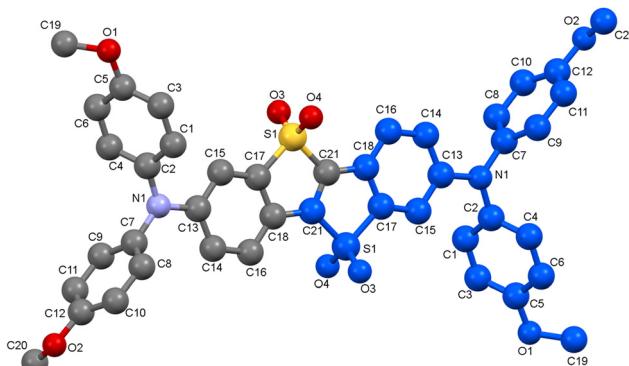


Fig. 3 **MPA₂-BTBTO₄**: a view of the asymmetric unit (half a molecule, drawn on the left hand side), showing the atom-labelling scheme and the colour setting by atomic species (*i.e.*, yellow – S, red – O, light blue – N, and grey – C); the other half of the molecule is shown in blue and consists of symmetry equivalent atoms, whose labelling is identical to that of the corresponding symmetry independent atoms. H atoms are omitted for clarity. Mercury⁸¹ software was used to generate this graphic.

integrated intensities, structure solution and Rietveld refinement) was successful for **MPA₂-BTBTO₄** and did not succeed for **PTz₂-BTBTO₄** due to the lower quality and resolution of the diffraction data in this case. **MPA₂-BTBTO₄** crystallized in the centrosymmetric space group *P*2₁/c (Table S5.1, ESI[†]). The asymmetric unit, consisting of 27 non-H atoms (chemical formula C₂₁H₁₇NO₄S), was characterized by a planar core (including the aromatic ring C13-C14-C16-C18-C17-C15 and three additional atoms, *i.e.*, S1, N1 and C21, see Fig. S5.2, ESI[†]), and two out-of-plane methoxyphenyl groups (torsion angles C1-C2-N1-C13 and C13-N1-C7-C8 equal to -59° and 86° , respectively, see Fig. S5.2 and Table S5.2, ESI[†]). A view of the refined crystal structure determined by EXPO is provided in Fig. 3, showing the asymmetric unit (*i.e.*, half a molecule, colour setting by atomic species) and its symmetry equivalent unit (half a molecule, monochromatic blue colour) completing the butterfly-shape molecule. Details on the *ab initio* structure solution process are accompanied by two tables providing the main crystallographic data (Table S5.1, ESI[†]), the refined fractional atomic coordinates and isotropic displacement parameter, bond distances and angles and torsion angles (Table S5.2, ESI[†]), which are all supplied in the ESI[†].

The crystal architecture was stabilized by a large number and variety of non-covalent intermolecular interactions acting cooperatively^{82–87} (see Fig. S5.3 and additional details described in the ESI[†]).

The weakness of the interactions between non-parallel rings is highlighted by the Hirshfeld surface generated by the software CrystalExplorer,⁸⁸ providing a useful tool for a three-dimensional representation of the main intermolecular interactions in the crystal (see Fig. S5.4, *i.e.*, the Hirshfeld surface mapped over d_{norm} , ESI[†]).

2.5 DFT results

Density functional theory (DFT) and time-dependent DFT (TD-DFT) can provide useful insights for understanding of photophysical characteristics of luminescent molecules. In this work we study the ground (S_0) as well as the singlet (S_1) excited state geometries of **POCz₂-BTBTO₄**, **PTz₂-BTBTO₄** and **MPA₂-BTBTO₄** to shed some light onto the delayed fluorescent properties of these luminophores. The geometry optimisations were performed using the PBE0/def2-svp⁸⁹ level of theory, while single point energy calculations used CAM-B3LYP/ZORA-def2-TZVP⁸⁹ following similar calculations recently performed for Ir(III) complexes.⁹⁰ For this task we used the Orca 5.0.3 software package.^{91,92}

At first, we study the ground (S_0) and excited state (S_1) geometries of **POCz₂-BTBTO₄**, **PTz₂-BTBTO₄** and **MPA₂-BTBTO₄** (Fig. 4). It is immediately apparent that the central acceptor core is flat, with the $>\text{SO}_2$ oxygen atoms being the only moieties out of plane. There are no fundamental structural differences between the S_0 and S_1 geometries, except perhaps for the relative orientation of donors with respect to the acceptor. At S_0 geometries both donors retain generally similar conformations against the acceptor core making them roughly equivalent. This equivalent function of donors is also reflected in the symmetric distribution of HOMOs in the ground state (Fig. 5). This equivalence or symmetry is broken in the S_1 geometry, where the two donors show evidently different conformations from one to another: the first one retaining a relatively similar orientation to that in the ground state and the other being twisted around the C–N axis, or deformed. In **POCz₂-BTBTO₄** and **MPA₂-BTBTO₄** this is expressed by a larger D–A angle, leading to a more orthogonal configuration, and therefore a lower energy CT state (S_1) energy associated with this donor. A CT state associated with the other donor is also present at a higher energy (*i.e.* S_2). In the ground state geometry, the first singlet excitation ($S_0 \rightarrow S_1$) is dominated by the HOMO \rightarrow LUMO transition and can be assigned a CT (**PTz₂-BTBTO₄**) or hybrid CT + LE (**POCz₂-BTBTO₄**, **MPA₂-BTBTO₄**) character. Interestingly, in **PTz₂-BTBTO₄** the configuration of both phenothiazine in the

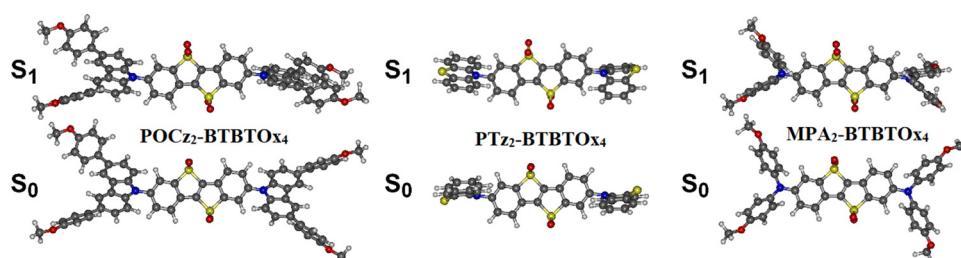


Fig. 4 Comparison between calculated ground (S_0) and excited state (S_1) geometries.



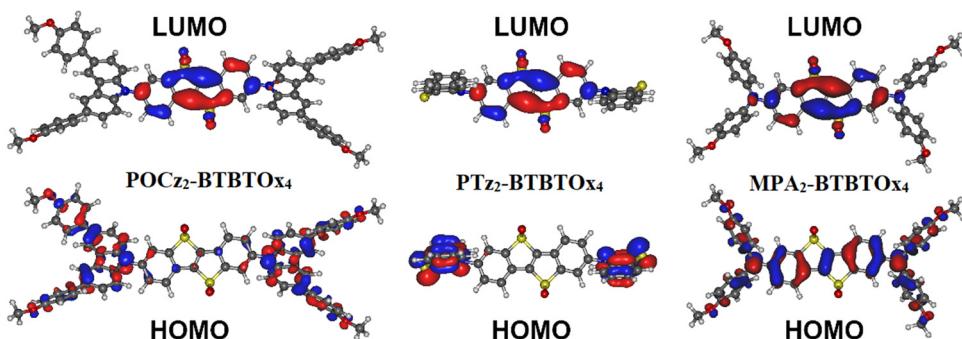


Fig. 5 HOMO and LUMO isosurfaces calculated at the S_0 geometry of $\text{POCz}_2\text{-BTBTOx}_4$, $\text{PTz}_2\text{-BTBTOx}_4$ and $\text{MPA}_2\text{-BTBTOx}_4$.

ground state is equatorial, while in the S_1 state one of the donors rearranges into a planar configuration. The said planar configuration serves as a stronger donor and contributes to the formation of the S_1 state, while the other phenothiazine unit in the equatorial configuration contributes to the S_2 . In both configurations however the D-A form a roughly orthogonal arrangement. Donor-acceptor systems featuring phenothiazine are notorious for displaying dual emissive behaviours.^{15,93,94} In the case of $\text{PTz}_2\text{-BTBTOx}_4$ two conformers of phenothiazine, equatorial and planar, coexist in one S_1 geometry giving rise to distinctive singlet CT excited states associated with either one of the two donors, as mentioned above. We hypothesize that this evident potential to switch between equatorial and planar geometries in the excited state may give rise to dual emissive behaviour in $\text{PTz}_2\text{-BTBTOx}_4$. Although the phenothiazine donors in $\text{PTz}_2\text{-BTBTOx}_4$ are shown to both be in their quasi-equatorial configuration in the S_0 this does not preclude higher energy conformers from being present, such as the quasi-axial forms.

TD-DFT singlet and triplet excitation energies and the respective orbital pairing calculated at the S_1 geometry are

shown in Table S6.1 (ESI[†]), in Fig. 6 for $\text{PTz}_2\text{-BTBTOx}_4$ and in Fig. S6.1 and S6.2 (ESI[†]). The general picture of the excited states is very similar in all three emitters with the T_1 state being generally of ${}^3\text{LE}_\text{A}$ (excited state localised on the acceptor) nature, while the S_1 state is associated with an intramolecular charge transfer (${}^1\text{CT}$) character. One may note S_1 and S_2 are associated with distinctive CT transitions involving different donor moieties. The ΔE_{ST} calculated directly from the S_1 and T_1 energies are: 0.53 eV in $\text{POCz}_2\text{-BTBTOx}_4$, 0.07 eV in $\text{PTz}_2\text{-BTBTOx}_4$, and 0.59 eV in $\text{MPA}_2\text{-BTBTOx}_4$. Given the small ΔE_{ST} in $\text{PTz}_2\text{-BTBTOx}_4$ one may reasonably expect this emitter to display TADF. At first the ΔE_{ST} for $\text{POCz}_2\text{-BTBTOx}_4$ and $\text{MPA}_2\text{-BTBTOx}_4$ appear too large to support potential TADF behaviour. However, a closer look at the reasons for the magnitude of ΔE_{ST} opens an alternative pathway to interpret these results. At the minimal S_1 geometry of $\text{PTz}_2\text{-BTBTOx}_4$ the donor and acceptor are nearly completely decoupled, hence the T_1 represents a 'pure' ${}^3\text{LE}_\text{A}$ state with an energy of 1.75 eV. The optimised S_1 geometry of $\text{POCz}_2\text{-BTBTOx}_4$ and $\text{MPA}_2\text{-BTBTOx}_4$ however shows a partial conjugation between the donor and acceptor. In this case the T_1 energy drops ever so slightly to 1.74 eV in $\text{POCz}_2\text{-BTBTOx}_4$ and more significantly to 1.51 eV in $\text{MPA}_2\text{-BTBTOx}_4$. We believe that, however, the influence of the partial donor-acceptor conjugation may be exaggerated in this case with respect to the real system. For example, the donors will be allowed to freely rotate around the C-N bonds due to the small activation energy for this motion. We believe that the contribution of configurations with more decoupled donor and acceptor pairs appearing in real systems may lead to the T_1 energy being closer to that of a fully decoupled system than that determined in this calculation. By using the energy of a 'pure' ${}^3\text{LE}_\text{A}$ state with an energy of 1.75 eV from $\text{PTz}_2\text{-BTBTOx}_4$ we estimate ΔE_{ST} of 0.51 eV for $\text{POCz}_2\text{-BTBTOx}_4$ and 0.35 eV for $\text{MPA}_2\text{-BTBTOx}_4$, hence demonstrating that TADF may be possible at least in $\text{MPA}_2\text{-BTBTOx}_4$. Spin-orbit coupling matrix elements (SOCME) between the lowest singlet and triplet states are shown in Table S6.2 (ESI[†]). They clearly demonstrate potential pathways for ISC and RISC within these systems. For example, in $\text{PTz}_2\text{-BTBTOx}_4$ the $\langle T_1 | \hat{H}_{\text{SO}} | S_1 \rangle$ and $\langle T_1 | \hat{H}_{\text{SO}} | S_2 \rangle$ are $\sim 0.2\text{--}0.5 \text{ cm}^{-1}$, one order of magnitude larger than $\langle T_2 | \hat{H}_{\text{SO}} | S_1 \rangle$ and $\langle T_2 | \hat{H}_{\text{SO}} | S_2 \rangle$. In this case the role of the T_1 (${}^3\text{LE}_\text{A}$) is necessary to promote RISC to the ${}^1\text{CT}$ state. Somewhat similarly, the $\langle T_1 | \hat{H}_{\text{SO}} | S_1 \rangle$ and $\langle T_1 | \hat{H}_{\text{SO}} | S_2 \rangle$

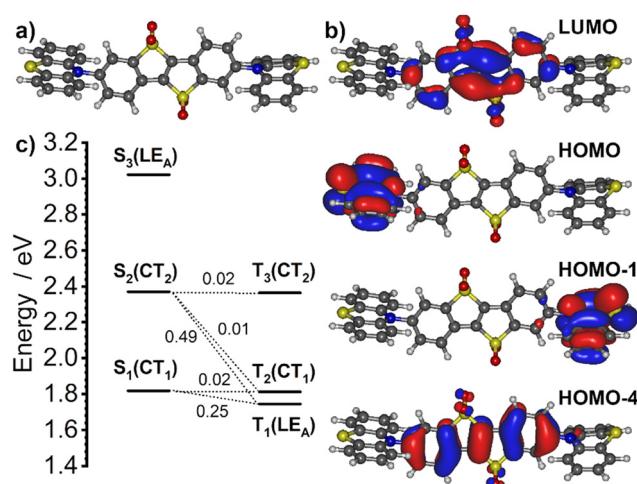


Fig. 6 TD-DFT calculations for $\text{PTz}_2\text{-BTBTOx}_4$ at S_1 geometry: (a) structure in the S_1 state; (b) isosurfaces of the relevant molecular orbitals; (c) excited state energy diagram with the orbital character of each of the excited states; the values and dotted lines represent SOCME in cm^{-1} between the indicated states.



in **POCz₂-BTBTO₄** and **MPA₂-BTBTO₄** are larger than other pairings due to the analogous orbital nature of these two states as in **PTz₂-BTBTO₄**.

2.6 Photophysical properties

In this section, we explore the photophysical characteristics of **PTz₂-BTBTO₄**, **MPA₂-BTBTO₄** and **POCz₂-BTBTO₄**, aiming to understand how different donor units influence their optical behaviour and thus their potential as TADF materials in OLEDs. Specifically, the three donor units, phenothiazine (PTz), dimethoxyphenylamine (MPA) and carbazole (Cz) derivative (POCz) exhibit different electron-donating and steric behaviours. We conducted a comprehensive study of these compounds using UV-vis absorption, steady-state and time-resolved fluorescence spectroscopy. The initial investigation involved studying the photophysical properties in diluted solution (10^{-5} M) in three solvents with different polarity: cyclohexane (CH), toluene (Tol) and dichloromethane (DCM). Then, we moved to the solid-state (as isolated molecules) by means of two polymer matrices with different polarity, namely zeonex and poly(methyl methacrylate) (PMMA). Finally, the steady-state photophysical properties of the neat films (drop casting) were also explored. A summary of the photophysical results for all three compounds can be found in Tables 3 and 4.

2.6.1 Absorption spectra. The UV-vis absorption spectra of the three compounds **PTz₂-BTBTO₄**, **MPA₂-BTBTO₄** and **POCz₂-BTBTO₄** were recorded in diluted solutions (10^{-5} M) of three solvents with different polarity: cyclohexane (CH), toluene (Tol) and dichloromethane (DCM) (Fig. 7). In all

systems, the lowest energy band is attributed to Intramolecular Charge Transfer (ICT) processes between the donor (D) and the acceptor (A) units. This finding is consistent with the TD-DFT calculations since it is identified as a CT or CT + LE HOMO-LUMO transition between the donor and acceptor units (Table S6.1, ESI[†]). Specifically, we observed that the CT band appears Gaussian in all cases, except for **POCz₂-BTBTO₄** in CH, where it is well-resolved indicating the presence of a hybrid localized charge transfer (HLCT or CT + LE) state, again in line with calculations. By increasing the solvent polarity, a red-shifted Gaussian emission is observed for all molecules, confirming the CT character of this transition. This shift is attributed to dipolar interactions with the solvent, favouring the stabilization of the CT state. Conversely, the peaks at higher energy remain unaffected by polarity and are associated with locally excited (LE) transitions on the donor or acceptor unit. Specifically, for **POCz₂-BTBTO₄**, the absorption band at ~ 290 nm is assigned to the $\pi-\pi^*$ localized absorption of Cz, as well as that at 330 nm.⁹⁵ For **PTz₂-BTBTO₄**, the absorption bands at $\lambda_{\text{max}} = 315$ and 330 nm, along with the shoulder at 290 nm, are assigned to the localized absorption of phenothiazine.⁹⁶ In the case of **MPA₂-BTBTO₄**, at higher energy, two bands are observed at 280 and 375 nm, corresponding to LE transitions of dimethoxyphenylamine. Lastly, in the deep UV region, the transitions between 225 and 260 nm are associated with LE states of the acceptors for all the systems.

2.6.2 Solution PL (steady-state and time-resolved). The photoluminescence (PL) spectra in diluted solutions measured in three solvents with increasing polarity (CH, Tol and DCM),

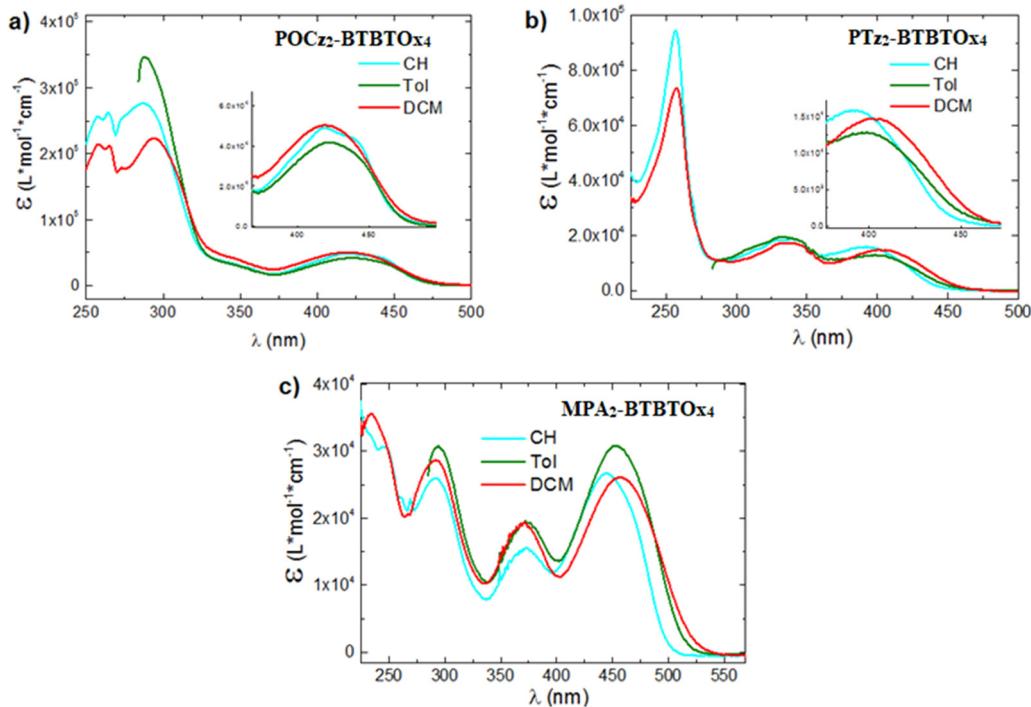


Fig. 7 UV-vis absorption spectra in CH (10^{-5} M, cyan), in Tol (10^{-5} M, green) and DCM (10^{-5} M, red) of (a) **POCz₂-BTBTO₄**, (b) **PTz₂-BTBTO₄**, and (c) **MPA₂-BTBTO₄**. In toluene, the UV-vis absorption below 285 nm is not reported since it is obscured by the solvent UV-vis absorption cut-off wavelength.



reveal distinct patterns among **POCz₂-BTBTOx₄**, **PTz₂-BTBTOx₄** and **MPA₂-BTBTOx₄** (Fig. 8). Notably, **POCz₂-BTBTOx₄** and **PTz₂-BTBTOx₄** exhibit two distinct bands (except in DCM where **PTz₂-BTBTOx₄** displays only one band), while **MPA₂-BTBTOx₄** shows a single band in all the three solvents. For all the samples, the low-lying band is the most intense and displays positive solvatochromic behaviour, typical for donor–acceptor (D–A) systems. In CH, its structured profile suggests a hybrid local and charge transfer (HLCT) character, while in toluene, the band becomes Gaussian and is red shifted due to the increased solvent polarity that stabilizes the CT state. Further increasing the polarity in DCM results in a red shift of the CT band for **POCz₂-BTBTOx₄** and **MPA₂-BTBTOx₄**. For **PTz₂-BTBTOx₄** a strong stabilization effect is responsible for the extinction of the CT emission. Concerning the higher-energy band, especially in **POCz₂-BTBTOx₄** (the inset in Fig. 8a), it remains unperturbed by solvent polarity, indicating locally excited (LE) character.

For deeper insights into the photophysical mechanism, decay profiles (Fig. S7.1, ESI†) were acquired, and lifetimes were determined (Table 2). We note that, in the cases of **POCz₂-BTBTOx₄** in CH and DCM, and **MPA₂-BTBTOx₄** in DCM, the decay collected for the lower energy band exhibits a bi-exponential decay, with the longer component assigned to the CT state, while the shorter one can be assigned to a HLCT state. In the other cases, *i.e.* for all systems in Tol, for **PTz₂-BTBTOx₄** in CH and DCM and for **MPA₂-BTBTOx₄** in CH, the decay

collected for the lower energy band exhibited a mono-exponential course, originating from the CT state. For **POCz₂-BTBTOx₄** and **PTz₂-BTBTOx₄** we also collected the decay for the LE band (higher energy, Fig. S7.1, ESI†), nevertheless, since the excitation is at 405 nm we acquired the decay at 430–450 nm and thus the double lifetime observed in some depends on the tail of the CT band (Table 2). The photoluminescence quantum yields (Φ_{PL}) were determined for all three compounds (Table 2). The values reduce upon increasing solvent polarity, which can be assigned to polarity-related stabilization of the excited state. The higher Φ_{PL} in CH is attributed to the presence of a HLCT transition which, in comparison to the CT transition, displays a larger HOMO–LUMO overlap and hence higher oscillator strength $f(S_1 \rightarrow S_0)$. Notably, Φ_{PL} exceeds 50% for **POCz₂-BTBTOx₄** and **MPA₂-BTBTOx₄**, while for **PTz₂-BTBTOx₄** it reaches only 3%, indicating a reduction in the donor–acceptor conjugation in the last example and thus of the transition oscillator strength. Furthermore, the effect of oxygen quenching on quantum yields and lifetimes was tested for all three compounds. However, after deoxygenation, none of the compounds showed intensity variation with long-lived emission, ruling out the possibility of TADF activity in solution.

2.6.3 Steady-state and time-resolved PL emission properties in solid polymer thin film matrices. We also explored the photoluminescence features of **POCz₂-BTBTOx₄**, **PTz₂-BTBTOx₄** and **MPA₂-BTBTOx₄** in the solid state by dispersing the samples at a low concentration (0.1% by weight) in two different polarity

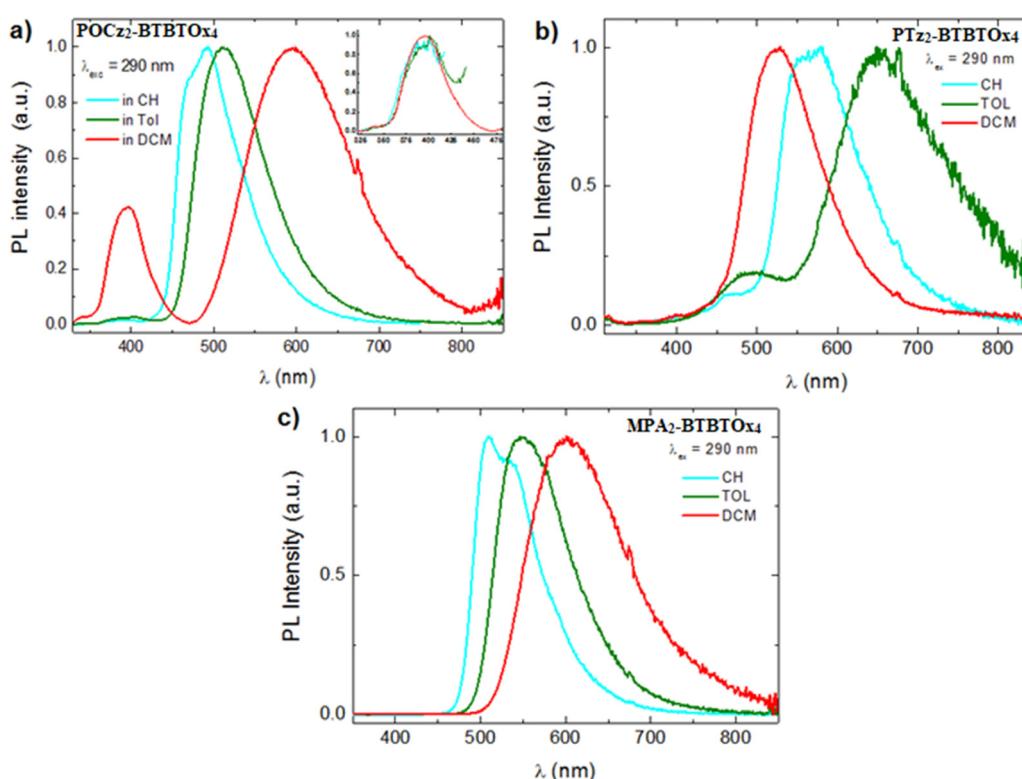


Fig. 8 Normalized PL spectra in CH (10^{-5} M, cyan), Tol (10^{-5} M, green) and DCM (10^{-5} M, red) of (a) **POCz₂-BTBTOx₄**, inset: normalized higher energy band, (b) **PTz₂-BTBTOx₄**, and (c) **MPA₂-BTBTOx₄**.



Table 2 Photophysical data of **POCz₂-BTBTO_x₄**, **PTz₂-BTBTO_x₄** and **MPA₂-BTBTO_x₄** in CH, Tol and DCM

	CH		Tol		DCM	
	Φ_{PL} (%)	τ (ns)	Φ_{PL} (%)	τ (ns)	Φ_{PL} (%)	τ (ns)
POCz₂-BTBTO_x₄	68.8	$\lambda_{Em} = 430$ nm 2.8(25%), 3.8(75%) $\lambda_{Em} = 500$ nm 2.7(23%), 4.9(77%)	51.2	$\lambda_{Em} = 430$ nm 1.0(7%), 5.4(93%) $\lambda_{Em} = 510$ nm 5.5(100%)	3.8	$\lambda_{Em} = 440$ nm 1.8(32%), 5.4(68%) $\lambda_{Em} = 600$ nm 1.4(94%), 5.4(6%)
PTz₂-BTBTO_x₄	2.7	$\lambda_{Em} = 450$ nm 3.2(100%) $\lambda_{Em} = 570$ nm 5.1(100%)	1.2	$\lambda_{Em} = 450$ nm 2.5(100%) $\lambda_{Em} = 600$ nm 4.1(100%)	0.3	$\lambda_{Em} = 450$ nm 1.3(60%), 4.2(40%) $\lambda_{Em} = 530$ nm 4.0(100%)
MPA₂-BTBTO_x₄	59.6	$\lambda_{Em} = 517$ nm 4.1(100%)	55.6	$\lambda_{Em} = 550$ nm 4.5(100%)	11.2	$\lambda_{Em} = 600$ nm 1.7(95%) 3.9(5%)

polymer matrices, namely Zeonex and PMMA. The steady-state emission of all the three compounds reveals distinct behaviours (Fig. 9). In Zeonex, the profile appears resolved with HLCT character while, in PMMA, it becomes Gaussian due to its higher polarity stabilizing the CT state. A noteworthy observation is the bathochromic shift of the PL emission of **MPA₂-BTBTO_x₄** in both polymers compared to **POCz₂-BTBTO_x₄** and **PTz₂-BTBTO_x₄**. We can also observe that **PTz₂-BTBTO_x₄** in Zeonex exhibits a broadened emission compared to PMMA, with the formation of a new shoulder at 550 nm, suggesting the presence of multiple emissive states.

The photophysical properties of all the three compounds in Zeonex were also investigated under deoxygenated conditions. In Fig. S7.2 (ESI[†]) we can note that while the emission spectrum of **POCz₂-BTBTO_x₄** and **MPA₂-BTBTO_x₄** remains almost unchanged, **PTz₂-BTBTO_x₄** in Zeonex reveals an additional intense band at lower energy. Further experiments, using various excitation wavelengths and doping concentrations (0.1, 1 and 5 wt%) (Fig. S7.3, ESI[†]), demonstrate that the lower energy PL band in **PTz₂-BTBTO_x₄** is affected by these parameters. Notably, the lower energy PL band gradually diminishes as the excitation shifts to longer wavelengths (λ_{ex} in Fig. S7.3, ESI[†]), resulting in fully Gaussian emission at $\lambda_{ex} = 400$ nm. This behaviour can be observed at all doping concentrations, with the lower energy band being markedly more pronounced at the highest load. Based on these findings, we can identify two distinct emissive species. Specifically, it exhibits

emission varying with excitation wavelength: one PL band evident for λ_{exc} (below 400 nm) and another for $\lambda_{exc} = 300\text{--}350$ nm. According to the DFT calculations, these two species can be potentially attributed to the two different phenothiazine conformers on the same molecule (planar and equatorial), aligning with previous reports on phenothiazine-substituted compounds.^{15,93,94} The increased presence of conformers at higher doping concentrations indicates that intermolecular interactions occurring in the condensed phase are crucial for the formation of lower energy emissive conformers. As shown in Table 3, **POCz₂-BTBTO_x₄** and **PTz₂-BTBTO_x₄** in PMMA display double the PLQY values in air compared to the same conditions in Zeonex, while that for **MPA₂-BTBTO_x₄** in air is very similar in both polymers. Furthermore, when comparing the Φ_{PL} of **POCz₂-BTBTO_x₄** in polymers with that in dilute solutions, it is evident that the Φ_{PL} is higher in CH and Tol than in both polymers, particularly in Zeonex. This potentially suggests an aggregation-caused quenching (ACQ) effect, which is more pronounced in Zeonex, probably due to the lower compatibility of this polymer with **POCz₂-BTBTO_x₄**. On the other hand, **PTz₂-BTBTO_x₄** displays a larger Φ_{PL} in both polymer matrices, especially in PMMA, than in solution, indicating that rigidochromic effects dominate. Finally, for **MPA₂-BTBTO_x₄** Φ_{PL} remains almost unchanged from solution to both polymer matrices, and this effect may be attributed to the presence of bulky dimethoxyphenylamine donors, which likely prevent both $\pi\text{--}\pi$ stacking and other non-radiative deactivation processes. We also studied

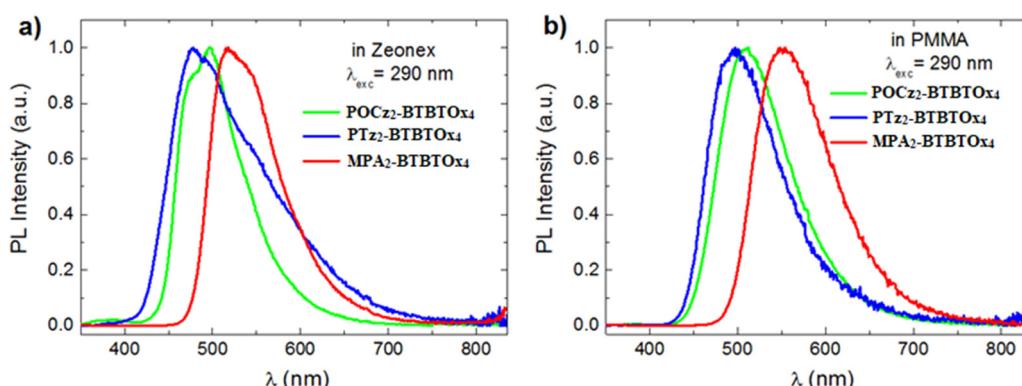
Fig. 9 Normalized PL spectra of **POCz₂-BTBTO_x₄**, **PTz₂-BTBTO_x₄** and **MPA₂-BTBTO_x₄** in: (a) Zeonex (0.1 wt%) and (b) PMMA (0.1 wt%).

Table 3 Photophysical results for **POCz₂-BTBTOx₄**, **PTz₂-BTBTOx₄** and **MPA₂-BTBTOx₄** in PMMA and Zeonex

	PMMA			Zeonex		
	%Φ _{PL} air/deox.	τ ₁ /τ ₂ (ns) deox.	τ ₁ /τ ₂ (ms) deox.	Φ _{PL} air/deox.	τ ₁ /τ ₂ (ns) deox.	τ ₁ /τ ₂ (μs) air/deox.
POCz₂-BTBTOx₄	44/59	λ _{em} = 500 nm 8.3(100%)	λ _{em} = 500 nm 0.3(18%), 1.7(82%) τ _{av} = 1.7	25/76	λ _{em} = 500 nm 4.1(59%), 6.0(41%) τ _{av} = 5.4	λ _{em} = 500 nm 36.4(36%) 194.1(64%) τ _{av} = 179
PTz₂-BTBTOx₄	18/30	λ _{em} = 490 nm 8.6(100%)	λ _{em} = 490 nm 0.5(38%), 3.1(61%) τ _{av} = 2.9	10/30	λ _{em} = 480 nm 1.9(20%), 4.2(80%) τ _{av} = 4.0 λ _{em} = 550 nm 2.9(44%), 5.8(56%) τ _{av} = 5.0	λ _{em} = 480 nm NO DF λ _{em} = 550 nm 87.4(61%), 253.3(39%) τ _{av} = 195
MPA₂-BTBTOx₄	58/85	λ _{em} = 560 nm 6.2(100%)	λ _{em} = 560 nm 0.3(25%), 1.7(75%) τ _{av} = 1.6	60/93	λ _{em} = 530 nm 4.9(100%)/5.0(100%) τ _{av} = 5.0	λ _{em} = 530 nm 7.4(71%), 88.5(29%) τ _{av} = 74.7

air = in aerated conditions; deox = deoxygenated conditions; τ_{av} = average lifetime.

photoluminescence quenching in both polymer matrices for all three emitters. Interestingly, after deoxygenation, the PL intensity increases for all three compounds in both polymer matrices (Table 3), thus suggesting that all three materials may present TADF properties. In particular, for **PTz₂-BTBTOx₄**, the Φ_{PL} in Zeonex films gradually decreases with increasing doping concentration. Still, the ratio Φ_{PL}^{air}/Φ_{PL}^{deox} (Table S7.2, ESI†) is higher for 0.1 wt% film upon deoxygenation, suggesting that around a concentration of 0.1 wt% in Zeonex, the formation of species with delayed fluorescence (DF) properties is favoured. We conducted time-resolved PL studies of all three compounds in deoxygenated thin film in Zeonex, where the Φ_{PL} in deoxygenated conditions is higher, and the resulting decay lifetimes are shown in Table 3. Additionally, we performed time-resolved emission spectroscopy (TRES) mode measurements, allowing the reconstruction of individual spectra at specific time delays (TD) (see the photophysical data in the ESI,† for details), for all three compounds in Zeonex (0.1 wt%). The time-resolved spectra at TD for all three compounds depicted in Fig. 10, display distinct behaviours among the three systems.

Specifically, for **POCz₂-BTBTOx₄** (Fig. 10a), the high-energy emission peak is visible only in the early times, attributed to a locally excited state (¹LE) from direct excitation and emission from the D or A moiety. At longer time delays (TD = 30 ns), the initial ¹LE emission disappears, and only the lower energy band attributed to CT emission remains invariant throughout the decay. This indicates luminescence from the singlet state for both prompt and delayed components, suggesting TADF origin of this emission.^{97,98} For **MPA₂-BTBTOx₄** (Fig. 10e), the emission spectra appear more Gaussian-shaped, remain invariant throughout the decay, suggesting TADF emission for this molecule in Zeonex at room temperature. For both **POCz₂-BTBTOx₄** and **MPA₂-BTBTOx₄**, PL decays were collected, and lifetimes were measured (Table 3), showing two characteristic average lifetimes (τ_{av}): one in the nano-second regime attributed to the prompt fluorescence (PF) and the other in the micro-/milli-second one due to TADF. However, as observed in the decay curves (Fig. 10b and f), it is important to note that for

both **POCz₂-BTBTOx₄** and **MPA₂-BTBTOx₄**, the contribution of the TADF appears rather insignificant. This is clearly visible through the relative counts of the longer component in the decay, below 10³, more than two orders of magnitude lower than the PF component. Additionally, a higher laser power is required to observe the DF component, especially in **POCz₂-BTBTOx₄**. These observations are consistent with the singlet-triplet energy gap obtained from the DFT calculations, which is particularly high for **POCz₂-BTBTOx₄**. Conversely, the analysis of spectra acquired for **PTz₂-BTBTOx₄** (Fig. 10c) reveals a different behaviour for different time delays. At early times (0–2 ns), the emission arises entirely from the higher energy emissive state (λ_{max} = 480 nm), while the emission associated with the low-energy emissive state (570 nm) appears after 5 ns, becoming dominant at TD = 25 ns. Upon increasing delay time (after 1 μs), only the state centred at 570 nm remains invariant, with the spectral shape almost invariant, even with an increased delay time up to a few milliseconds. This behaviour is attributed to the presence of TADF, observed in the low-energy emissive state only,^{97,98} which is attributed, according to DFT calculations, to the conformer with phenothiazine in the planar configuration. Additional confirmations come from the decay profiles (Fig. 10d) collected at both emission peaks (λ = 480 nm and 570 nm, respectively), where a strong long-lived DF component (*i.e.* significantly more intense than in the case of the other two emitters) is present only for collection at 570 nm, while for collection at 480 nm, only a short decay typical of prompt fluorescence is detected. This pattern implies that at 0.1 wt% concentration, the higher energy emissive state (with phenothiazine equatorial) is more abundant, overshadowing the prompt fluorescence of the low-energy emissive state. Nonetheless, with longer TD, the low-energy emissive associated to the planar phenothiazine conformer, becomes discernible since it is the sole emitting state exhibiting delayed fluorescence. We have also carried out time-resolved experiments at 77 K (Fig. S7.5 and S7.6, ESI†), which allow us to gain more insight into the photophysics of these materials. However, we were unable to obtain reliable results for



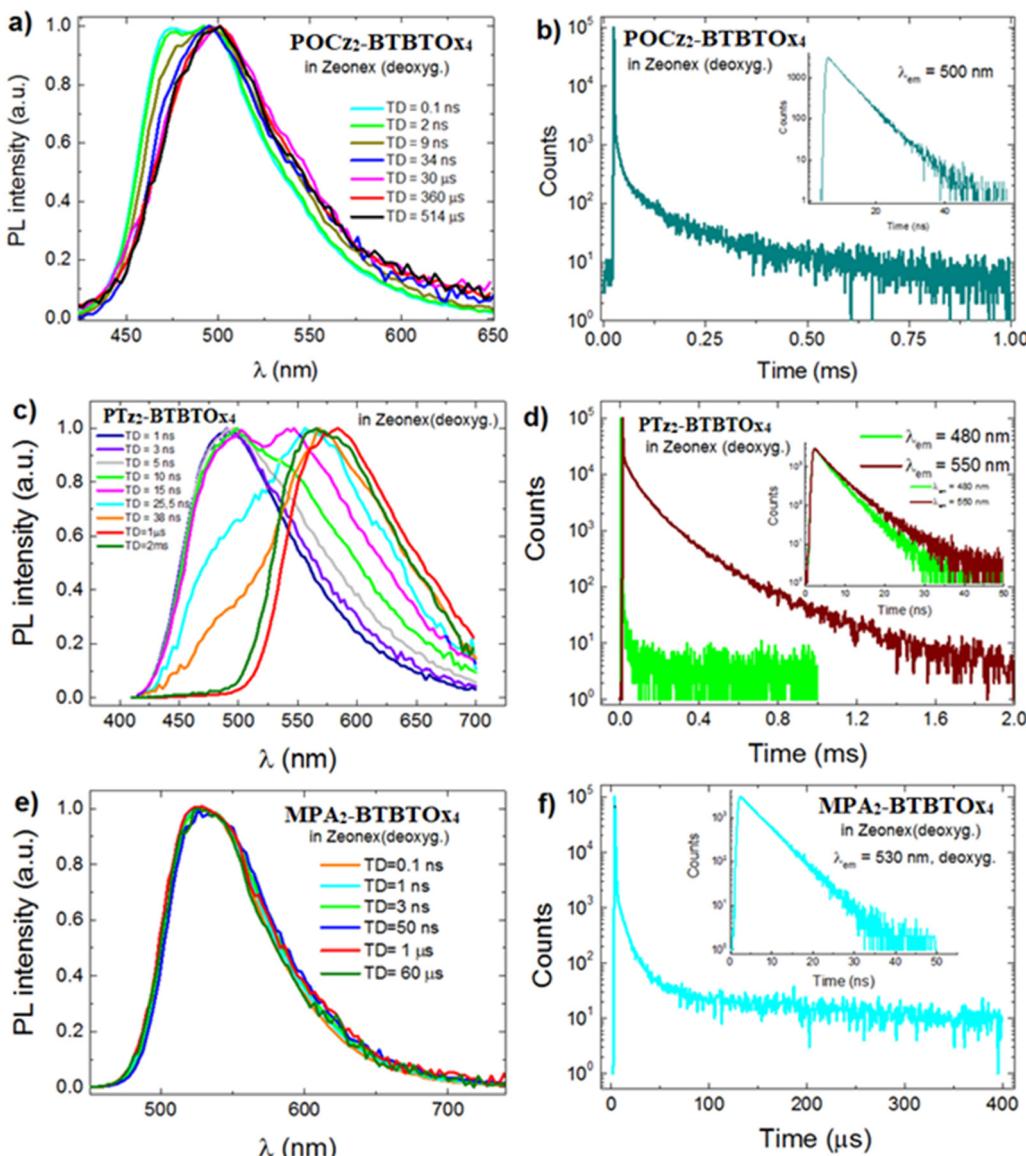


Fig. 10 (a) Time-resolved emission spectra in Zeonex (0.1 wt%) of (a) **POCz₂-BTBTO₄**, (c) **PTz₂-BTBTO₄**, and (e) **MPA₂-BTBTO₄**. PL decay in Zeonex (0.1 wt%) in the microsecond scale (insets: decay in the nanosecond scale) of (b) **POCz₂-BTBTO₄**, (d) **PTz₂-BTBTO₄**, and (f) **MPA₂-BTBTO₄**.

Table 4 Photophysical data for **POCz₂-BTBTO₄**, **PTz₂-BTBTO₄** and **MPA₂-BTBTO₄** in neat film

Compound	Absorption (λ_{max} , nm)	Emission (λ_{max} , nm)	% Φ_{PL}
POCz₂-BTBTO₄	267, 296, 347(s), 439	560	22
PTz₂-BTBTO₄	262, 341, 416, 600	516, 630	1.2
MPA₂-BTBTO₄	293, 372, 467, 632	593	1.3

MPA₂-BTBTO₄ and **POCz₂-BTBTO₄**. This is certainly related to the very weak delayed fluorescence in the two molecules and could be due either to an inefficient ISC or to the presence of non-radiative deactivation channels that are also efficient at 77 K. On the other hand, we were able to observe phosphorescence for **PTz₂-BTBTO₄** allowing us to estimate a ΔE_{ST} of 0.1 eV

(Fig. S7.5, ESI†) between the triplet and the singlet resulting from the energetically lower photoluminescence component exhibiting TADF. We have also determined the K_{RISC} to be on the order of 10^4 s^{-1} . For the method previously used by some of the current authors⁹⁹ $K_{\text{RISC}} = 0.6 \times 10^4 \text{ s}^{-1}$, while for a more simplified approach,¹⁰⁰ $K_{\text{RISC}} = 0.6 \times 10^4 \text{ s}^{-1}$. Due to the overall extremely low TADF intensity in the other two emitters we were unable to determine the K_{RISC} values. In conclusion, the photophysical study is in agreement with TD-DFT calculations. For example, the best compound in terms of TADF properties is **PTz₂-BTBTO₄**, while **MPA₂-BTBTO₄** presents less impressive TADF behaviour. At the same time, **POCz₂-BTBTO₄** shows the worst TADF properties. This ordering agrees with the ΔE_{ST} values predicted by TD-DFT.



2.6.4 Steady-state photophysical properties in neat films.

In this section we present a short study of the photophysical properties of the three emitting materials in neat films to assess their potential as self-hosted emitters in OLED devices. First, their UV-Vis properties were investigated, as shown in Fig. S7.4 (ESI[†]), in comparison to the isolated molecules in CH solution. While the higher energy transitions associated with the LE states retain their location found in solvents, all pure films show a clear bathochromic shift in the lower energy band associated with the CT transition. This red shift is consistent with the stabilizing effect induced by the dipoles of neighbouring molecules in the neat film. Notably, an additional weak broad band at lower energy is observed, in both **POCz₂-BTBTO₄** and **PTz₂-BTBTO₄** neat films, possibly indicating the formation of new aggregate-induced electronic states.

The PL spectra of the three emitting materials in neat films (Fig. 11) were compared with those of isolated molecules dispersed in polymer matrices (Zeonex and PMMA, Fig. 9). **POCz₂-BTBTO₄** and **MPA₂-BTBTO₄** neat films show Gaussian shaped emissions with a bathochromic shift of about 50 nm compared to PMMA. In addition, **POCz₂-BTBTO₄** shows a tail in the red region of the PL (700–800 nm), possibly associated with emission from aggregates. Conversely, the **PTz₂-BTBTO₄** neat film shows two distinct bands, one less intense at higher energy (525 nm) and another much more intense at 625 nm, probably due to different molecular conformers of the phenothiazine unit. The PL of the lower energy conformer is more intense in the neat film due to favoured Förster energy transfer between neighbouring molecules. We also determined the Φ_{PL} of compounds in neat films which is summarized in Table 5. Only **POCz₂-BTBTO₄** maintains a good Φ_{PL} in neat film (22%), compared to that in Zeonex, and half of that in PMMA, indicating minimal self-quenching. On the other hand, self-quenching is pronounced in **PTz₂-BTBTO₄** and **MPA₂-BTBTO₄**, with Φ_{PL} dropping to around 1% in neat film. The bulky POCz moieties linked to the BTBTO₄ in **POCz₂-BTBTO₄** likely prevent self-quenching in the solid state by hindering close packing of molecules, thereby reducing non-radiative

pathways *via* strong π - π stacking interactions. Based on these observations, **POCz₂-BTBTO₄** is the only emitting molecule suitable for use in neat film form for self-hosted OLED devices. Furthermore, the neat phase can be used to achieve more red-shifted electroluminescence.

2.7 OLED devices

Proof of concept OLED devices with a simple structure were fabricated using **PTz₂-BTBTO₄**, **MPA₂-BTBTO₄** and **POCz₂-BTBTO₄** in the emitting layer. In particular, these materials have been tested as neat emitting layers, avoiding the use of a host material and thus simplifying the device architecture. The OLEDs consist of indium-tin-oxide (ITO) as the anode, poly(3,4-ethylenedioxythiophene) doped with poly(styrene sulfonate) (PEDOT:PSS, 35 nm) as the hole transport layer (HTL), poly(9-vinylcarbazole) (PVK) as the electron blocking layer (EBL, 15 nm), an emitting layer (EML, 35 nm – **PTz₂-BTBTO₄** or **MPA₂-BTBTO₄** or **POCz₂-BTBTO₄**), 1,3,5-tris(1-phenyl-1*H*-benzimidazol-2-yl)benzene (TPBi) as the electron transport layer (ETL, 50 nm), and LiF (1 nm) and Al (100 nm) as the cathode. The device architecture is shown in Fig. 12a. A summary of all OLED characteristics is reported in Table 5.

A comparison of the performance of the three OLEDs shows that the **MPA₂-BTBTO₄**-based device has a higher current density than that using **PTz₂-BTBTO₄** and **POCz₂-BTBTO₄** in the emitting layer (Fig. 12b). The maximum luminance values are very similar for the devices based on **MPA₂-BTBTO₄** and **POCz₂-BTBTO₄**, while they are considerably lower for the device based on **PTz₂-BTBTO₄**. This results in higher efficiency for the **POCz₂-BTBTO₄**-based device, with a maximum current efficiency of about 4 cd A⁻¹ compared to significantly lower values for **PTz₂-BTBTO₄** and **MPA₂-BTBTO₄**, of 0.17 and 1.1 cd A⁻¹, respectively (Fig. 12c). Our results are in line with the photophysical study of **PTz₂-BTBTO₄**, **MPA₂-BTBTO₄** and **POCz₂-BTBTO₄** in neat film (Fig. 12 and Table 5). **POCz₂-BTBTO₄** exhibits the highest photoluminescence quantum yield in neat film (around 20%), while **PTz₂-BTBTO₄** and **MPA₂-BTBTO₄** undergo significant self-quenching phenomena, with quantum yields in the order of a few percent. The difference in the turn on voltage values of these devices is probably related to a different charge balance, due to the combined effect of the energy levels and the peculiar charge carrier mobilities of the active materials. These results agree with the charge carrier mobility of our emitters, which is higher for **MPA₂-BTBTO₄** and **POCz₂-BTBTO₄** (1.1×10^{-6} cm² V⁻¹ s⁻¹) and about two orders of magnitude lower for **PTz₂-BTBTO₄** (5.2×10^{-8} cm² V⁻¹ s⁻¹). The electroluminescence spectra are also shown in Fig. 12d and the peak emission wavelengths confirm the trend observed in the photoluminescence spectra of the neat film (Fig. 11). Taking into account our results, the best performing material **POCz₂-BTBTO₄** was also tested with an inkjet-printed emissive layer. The ink formulation was selected according to our recent work.¹⁰¹ A comparison between the devices obtained by spin coating and inkjet printing the active layer is shown in Fig. 12e and f. As reported in our previous work, solution processing of EML (spin coating

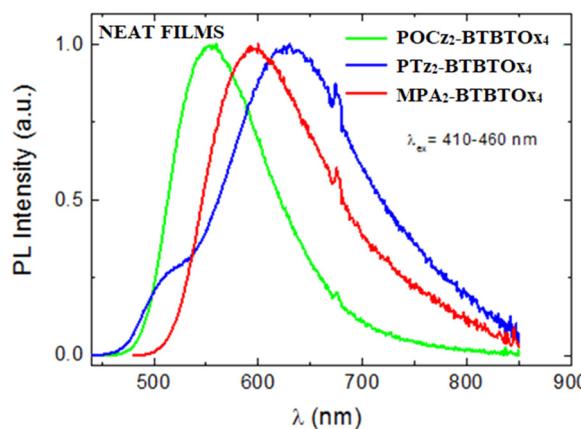


Fig. 11 Normalized PL spectra of **POCz₂-BTBTO₄**, **PTz₂-BTBTO₄** and **MPA₂-BTBTO₄** in neat films.



Table 5 Summary of the main OLED characteristics, including external quantum efficiency (EQE) and exciton utilization efficiency (EUE)

Emitting layer	Current density (mA cm ⁻²) at max efficiency	Max luminance (cd m ⁻²)	Current efficiency (cd A ⁻¹) @ 100 cd m ⁻²	Current efficiency (cd A ⁻¹) @ 1000 cd m ⁻²	Turn on voltage (@ 10 cd m ⁻²)	Peak wavelength (nm)	EML Φ_{PL} (%)	EQE (%)	EUE (%)
POCz₂-BTBTTox₄ spin coated	0.48@4.2 V	5016@8 V	3.8	3.35	4 V	553	28.9	1.19	20.6
POCz₂-BTBTTox₄ printed	5.5@5.5 V	2524@10 V	3.46	3.35	4 V	553	25.8	1.01	19.6
PTz₂-BTBTTox₄ spin coated	1.23@4 V	381@10 V	0.17	n.a.	4.8 V	624	2.1	0.14	33.3
MPA₂-BTBTTox₄ spin coated	0.47@3 V	3733@7 V	1.13	0.97	3.1 V	583	8.52	0.45	26.7

or printing) can cause a slight redissolution of the underlying PVK-based EBL layer, resulting in a blurred/mixed interface between the EBL and the EML. This, therefore, affects the electrical characteristics of the printed device, introducing slight differences between OLEDs with printed and spin coated EML. Indeed, we note that the current density is lower for the printed EML (Fig. 12e), and similarly, the luminance is also lower than that with the spin coated EML. This is probably due to a slight difference in the total thickness of the PVK-EML bilayer, as a consequence of the different deposition technique. As a result, the efficiency of the device with the spin coated active layer is slightly higher than one with the printed film, and the maximum efficiency of the latter is shifted to higher voltages. In any case, the performances of the two devices are comparable, demonstrating the quality of the printing process for the deposition of active layers in non-doped OLED devices. Table 5 also reports the external quantum efficiency (EQE) and exciton utilization efficiency (EUE, η_e) values for each device (calculated as described in the ESI,† Section 8, OLED devices). EQE and EUE values are in line with the photophysical study of **PTz₂-BTBTTox₄**, **MPA₂-BTBTTox₄** and **POCz₂-BTBTTox₄**.

As expected, the photoluminescence quantum yields of EMLs are higher than those measured for neat films, with a particularly strong self-quenching in the case of **PTz₂-BTBTTox₄**. Although from the EQE point of view **PTz₂-BTBTTox₄** and **MPA₂-BTBTTox₄** show the lowest performances (0.14% and 0.45%, respectively) compared to **POCz₂-BTBTTox₄** (1.19%), the related EUE values exceed the spin-statistic limitation of 25% for fluorescent materials. This suggests the presence of a triplet-harvesting mechanism in line with TADF behavior in these two materials, in agreement with our photophysical study. The electroluminescence spectra are shown in Fig. 12d, and the peak emission wavelengths are in line with the photoluminescence spectra of the neat film (Fig. 11). As already highlighted, the wet deposition process of the EML causes a partial redissolution of the PVK. This is confirmed by the blue shift of the EL peaks with respect to the PL peaks of the neat films, for all materials, due to the presence of PVK, which dilutes the active materials inside the EMLs. All the EL spectra show a weak band at around 400 nm, attributed to PVK or TPBi emission. In our opinion, considering that EMLs are virtually non-doped the presence of such a peak, highlights a slight

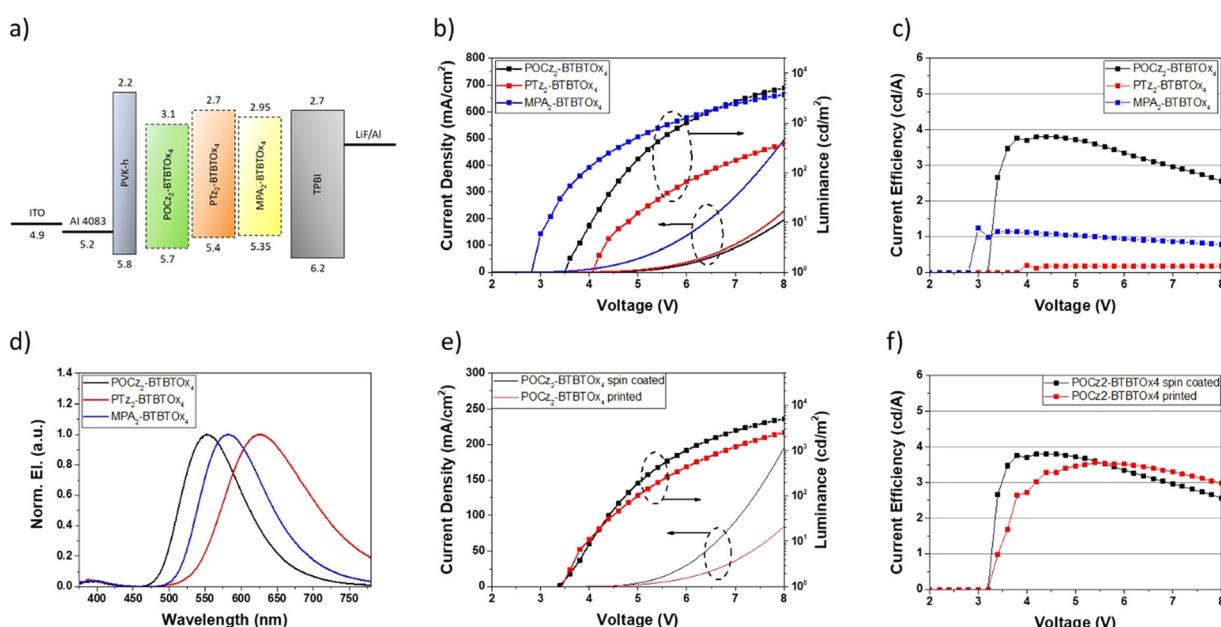


Fig. 12 Device architecture and characterization: (a) energy level diagram for the fabricated OLEDs using **POCz₂-BTBTTox₄** or **PTz₂-BTBTTox₄** or **MPA₂-BTBTTox₄** as the EML; (b) device current density and luminance for the three different emitting layers; (c) the current efficiency of OLEDs; (d) electroluminescence spectra; (e) current density and luminance comparison between the OLEDs with spin coated and printed **POCz₂-BTBTTox₄**; (f) comparison of current efficiency for spin coated and printed **POCz₂-BTBTTox₄**-based OLEDs.



imbalance in the charge injection, which causes excitonic recombination near one of the interfaces between the EML and the HTL (or ETL).

3. Conclusion

In summary, we designed and synthesized three new organic luminescent molecules with a D-A-D electronic structure and based on the [1]benzothieno[3,2-*b*]benzothiophene-tetraoxide **BTBTO_x₄** as the acceptor unit A. Three donor units D with different electron-donating capabilities and structural complexity were selected to be coupled with the acceptor A by the microwave-assisted Buchwald–Hartwig reaction, yielding **PTz₂-BTBTO_x₄**, **MPA₂-BTBTO_x₄** and **POCz₂-BTBTO_x₄**. Cyclic voltammetry and charge carrier mobility measurements were carried out to investigate the electrical properties of compounds, X-ray analysis was performed for determining the crystal structure. UV-vis absorption, steady-state fluorescence and time resolved fluorescence spectroscopy were used to investigate photophysical properties of the three organic emitters studied in this work. Theoretical studies were carried out to aid the photophysical characterization. OLED devices were fabricated to analyse the luminescence properties of the new organic emitters as self-hosted active matrices. All three organic emitters show high electrochemical stability with reversible oxidation waves. **MPA₂-BTBTO_x₄**, which can be obtained with a suitable degree of crystallinity, was selected as a reference molecule for X-ray analysis. Crystallographic data reveal a butterfly-shape molecule with a planar core (**BTBTO_x₄**) and out-of-plane *p*-methoxyphenyl groups of the donor unit (DMeOPA), with torsion angles (C1–C2–N1–C13 and C13–N1–C7–C8) of -59° and 86° , respectively. Steady-state and time-resolved photoluminescence studies in polymer matrices (Zeonex and PMMA) revealed a noteworthy increase in PL efficiency upon deoxygenation for all three organic emitters, especially in PMMA. We demonstrate the pronounced TADF properties of the three studied luminescent molecules representing a new class of organic emitting materials. We carried out preliminary studies of photophysical properties in neat films, with the aim of assessing the potential of this class of compounds as emitters in solution-processed self-hosted OLEDs. In **PTz₂-BTBTO_x₄** and **MPA₂-BTBTO_x₄** a pronounced self-quenching can be observed with a Φ_{PL} as low as 1%. In contrast, **POCz₂-BTBTO_x₄** reveals a minimal self-quenching with a capability to maintain a good Φ_{PL} (22%), comparable to that in Zeonex and half of that in PMMA. As a proof of concept, we tested the new organic compounds in neat films serving as an active matrix in simple self-hosted OLED devices, evaluating their optoelectronic characteristics and exciton utilization efficiencies. Although the performances of OLEDs are not in line with the state of the art, the purpose of our work was to demonstrate the possibility of employing this new acceptor as a building block in new emitters used in printed devices. Starting from this study, we plan to develop more efficient printable systems, with higher photoluminescence quantum yields and lower self-quenching, to be used as a neat film EML, thereby simplifying the device structure and minimizing the production

costs. Indeed, these are key factors in developing fabrication processes towards solution-based techniques.

Author contributions

M. Montrone: synthesis and characterization of organic emitters. A. Maggiore: design of photophysical experiments, supervision of the photophysical study and data analysis, writing the manuscript. A. Moliterni: X-ray data analysis, writing the manuscript. P. Pander: computational analysis, supplementary photophysical studies, writing the manuscript. M. Pugliese: OLED device fabrication and characterization, writing the manuscript. A. L. Capodilupo: CV analysis and chemico-structural characterization. S. Gambino: charge carrier mobility measurements, writing the manuscript. C. T. Prontera: OLED device fabrication. V. Valenzano: photophysical experiments. F. Mariano: OLED device fabrication. G. Accorsi: supervision of the photophysical data. T. Sibillano: X-ray data collection, writing of the manuscript. C. Giannini: supervision of X-ray data analysis and writing of the manuscript. G. Gigli: found acquisition, conceptualization and supervision of physical data. A. Cardone: design of organic emitters, original draft, writing review & editing. V. Maiorano: supervision, review and funding acquisition. All authors participated in the general discussion.

Data availability

The data supporting this article have been included as part of the ESI.† Crystallographic data of **BDMeOPA-BTBTO_x₄** are deposited at the Cambridge Crystallographic Data Centre, under deposition number CCDC 2362085 and can be obtained free of charge *via* <https://www.ccdc.cam.ac.uk/structures/>.†

Conflicts of interest

There are no conflicts to declare.

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